Supporting Information for

Self-Assembled Poly(ethylene glycol) Buffer Layers in Polymer Solar Cells: Toward Superior Stability and Efficiency

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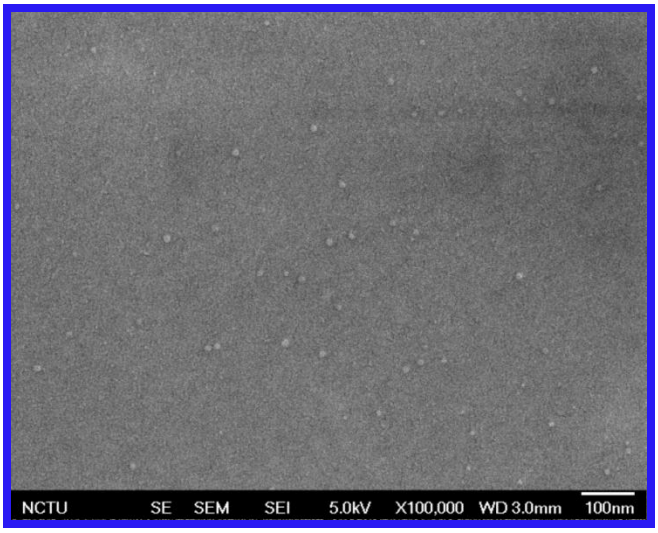

Figure S1. SEM image of the P3HT:PCBM thin film blended with PEG-6000 (1:1:0.1, wt%).

Table S1. Electrical characteristics of the P3HT:PCBM-based devices fabricated with PEGs on PEDOT:PSS and MoO_3 surfaces.

Substrate (Surface energy)[a]	Condition[b]	V_{oc} (V)	J_{sc} (mA cm^{-2})	FF	PCE
PEDOT:PSS (77.8 mN m^{-1})	Without PEG	0.49	8.36	54%	2.3%
	With PEG	0.59	9.25	65%	3.6%
MoO_3 (362.2 mN m^{-1})	Without PEG	0.45	6.53	53%	1.6%
	With PEG	0.15	0.60	26%	0.02%

[a]Surface energies were calculated using the Zisman model. [b]Photoactive layer contained either 0 or 10% PEG-400.

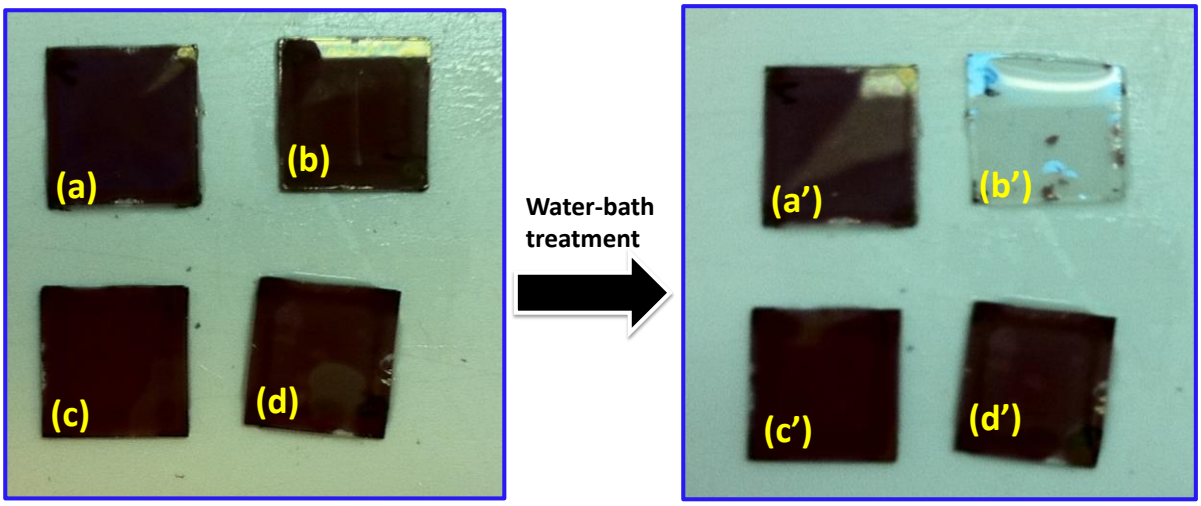

Figure S2. Photographs of P3HT:PCBM films prepared (b, b′, d, d′) with and (a, a′, c, c′) without 10% PEG-400, deposited on (a, a′, b, b′) MoO_3 and (c, c′, d, d′) PEDOT:PSS, (a–d) before and (a′–d′) after water-bath treatment.